P-Channel Power MOSFET

-20V, -4.7A, 50mΩ

FEATURES

- Halogen-free
- Suited for 1.8V drive applications
- Low profile package

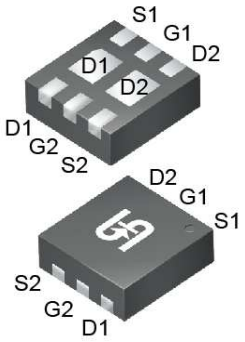
APPLICATION

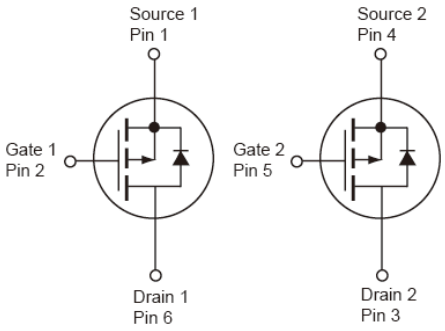
- Battery Pack
- Load Switch

KEY PERFORMANCE PARAMETERS			
PARAMETER		**VALUE**	**UNIT**
V_{DS}		-20	V
$R_{DS(on)}$ (max)	V_{GS} =- 4.5V	50	mΩ
	V_{GS} = -2.5V	65	
	V_{GS} = -1.8V	85	
Q_g		9.6	nC

Pb-Free RoHS COMPLIANT HALOGEN FREE

TDFN2x2





Notes: Moisture sensitivity level: level 3. Per J-STD-020

ABSOLUTE MAXIMUM RATINGS (T_A = 25°C unless otherwise noted)				
PARAMETER		**SYMBOL**	**LIMIT**	**UNIT**
Drain-Source Voltage		V_{DS}	-20	V
Gate-Source Voltage		V_{GS}	±10	V
Continuous Drain Current (Note 1)	T_C = 25°C	I_D	-4.7	A
	T_C = 100°C		-2.82	
Pulsed Drain Current (Note 2)		I_{DM}	-18.8	A
Total Power Dissipation @ T_C = 25°C		P_{DTOT}	0.62	W
Operating Junction and Storage Temperature Range		T_J, T_{STG}	- 55 to +150	°C

THERMAL PERFORMANCE			
PARAMETER	**SYMBOL**	**LIMIT**	**UNIT**
Junction to Ambient Thermal Resistance	$R_{\Theta JA}$	200	°C/W

Notes: $R_{\Theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistances.$R_{\Theta JA}$ is guaranteed by design while $R_{\Theta CA}$ is determined by the user's board design. $R_{\Theta JA}$ shown below for single device operation on FR-4 PCB in still air.

ELECTRICAL SPECIFICATIONS (T_A = 25°C unless otherwise noted)						
PARAMETER	**CONDITIONS**	**SYMBOL**	**MIN**	**TYP**	**MAX**	**UNIT**
Static (Note 3)						
Drain-Source Breakdown Voltage	V_{GS} = 0V, I_D = -250μA	BV_{DSS}	-20	--	--	V
Gate Threshold Voltage	V_{DS} = V_{GS}, I_D = -250μA	$V_{GS(TH)}$	-0.3	-0.6	-0.8	V
Gate Body Leakage	V_{GS} = ±10V, V_{DS} = 0V	I_{GSS}	--	--	±100	nA
Zero Gate Voltage Drain Current	V_{DS} = -20V, V_{GS} = 0V	I_{DSS}	--	--	-1	μA
Drain-Source On-State Resistance	V_{GS} = -4.5V, I_D = -3A	$R_{DS(ON)}$	--	42	50	mΩ
	V_{GS} = -2.5V, I_D = -2A		--	57	65	
	V_{GS} = -1.8V, I_D = -1A		--	75	85	
Forward Transconductance	V_{DS} = -10V, I_D = -3A	g_{fs}	--	7	--	S
Dynamic (Note 4)						
Total Gate Charge	V_{DS} = -10V, I_D = -3.0A, V_{GS} = -4.5V	Q_g	--	9.6	13	nC
Gate-Source Charge		Q_{gs}	--	1.6	2	
Gate-Drain Charge		Q_{gd}	--	2	4	
Input Capacitance	V_{DS} = -10V, V_{GS} = 0V, f = 1.0MHz	C_{iss}	--	850	1230	pF
Output Capacitance		C_{oss}	--	70	100	
Reverse Transfer Capacitance		C_{rss}	--	55	80	
Switching (Note 5)						
Turn-On Delay Time	V_{DD} = -10V, R_{GEN} = 25Ω, I_D = -1A, V_{GS} = -4.5V,	$t_{d(on)}$	--	6	11	ns
Turn-On Rise Time		t_r	--	21.6	41	
Turn-Off Delay Time		$t_{d(off)}$	--	51	97	
Turn-Off Fall Time		t_f	--	13.8	26	
Source-Drain Diode (Note 3)						
Continuous Source Current	V_G = V_D = 0V, Force Current	I_S	--	--	-4.7	A
Pulsed Source Current		I_{SM}	--	--	-18.8	A
Forward On Voltage	I_S = -1.0A, V_{GS} = 0V	V_{SD}	--	--	-1.0	V

Notes:

1. Current limited by package
2. Pulse width limited by the maximum junction temperature
3. Pulse test: PW ≤ 300μs, duty cycle ≤ 2%
4. For DESIGN AID ONLY, not subject to production testing.
5. Switching time is essentially independent of operating temperature.

ORDERING INFORMATION

PART NO.	PACKAGE	PACKING
TSM500P02DCQ RFG	TDFN 2x2	3,000pcs / 7” Reel

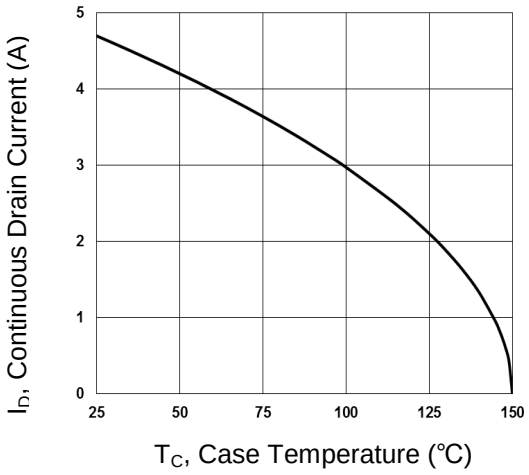
Note:

1. Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
2. Halogen-free according to IEC 61249-2-21 definition

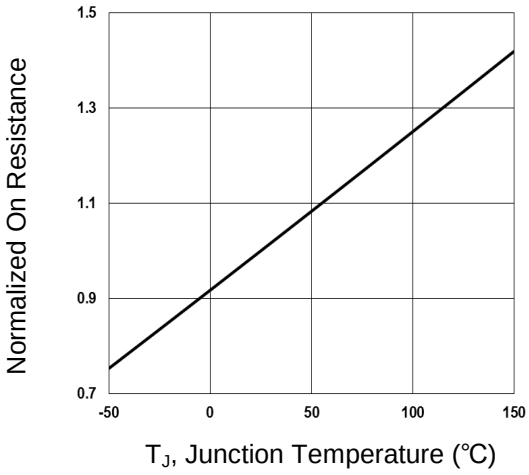
CHARACTERISTICS CURVES

(T_C = 25°C unless otherwise noted)

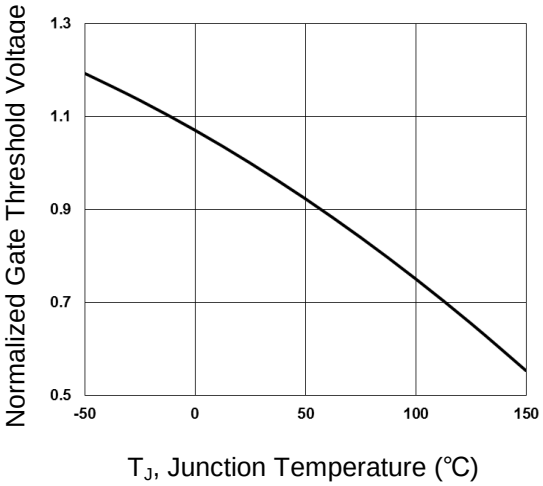
Continuous Drain Current vs. Tc



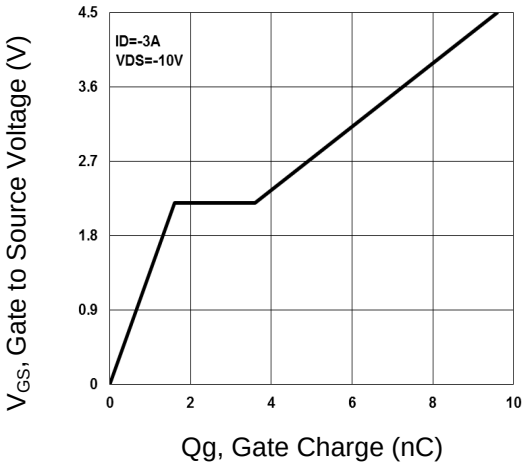
Normalized RDSON vs. T_J



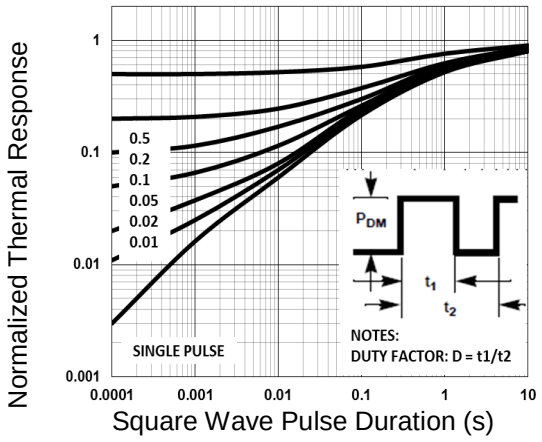
Normalized V_{th} vs. T_J



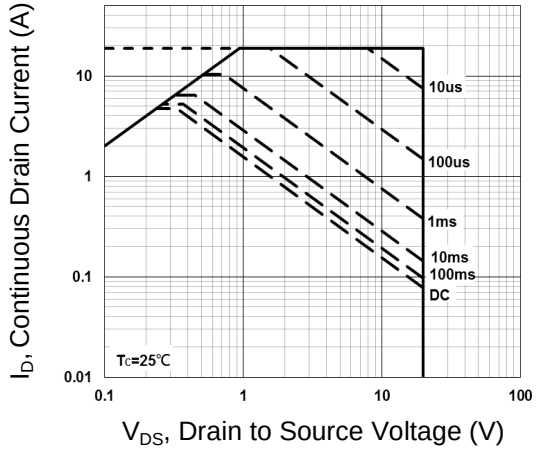
Gate Charge Waveform



Normalized Transient Impedance

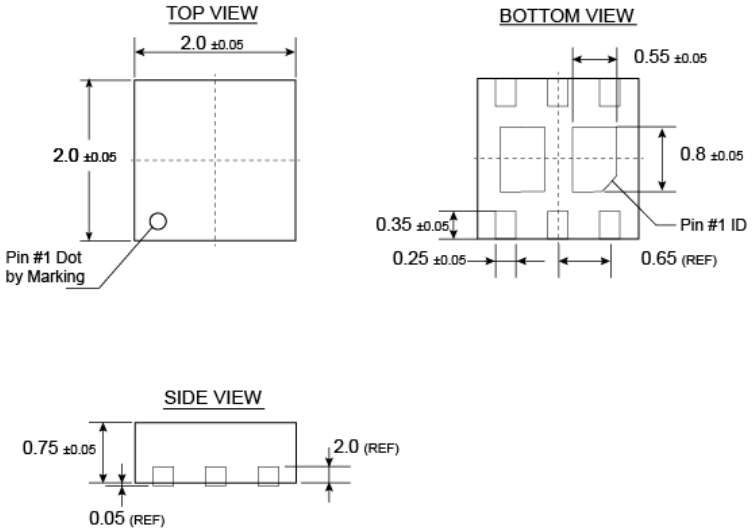


Maximum Safe Operation Area

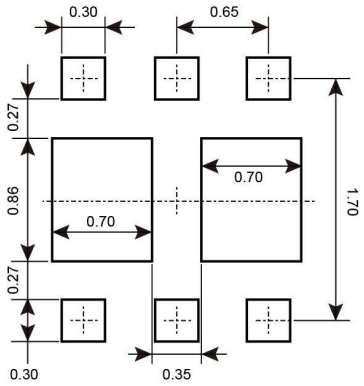


PACKAGE OUTLINE DIMENSIONS (Unit: Millimeters)

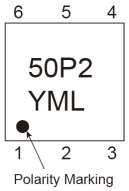
TDFN2x2



SUGGESTED PAD LAYOUT (Unit: Millimeters)



MARKING DIAGRAM



Y = Year Code
M = Month Code for Halogen Free Product

O	=Jan	**P**	=Feb	**Q**	=Mar	**R**	=Apr
S	=May	**T**	=Jun	**U**	=Jul	**V**	=Aug
W	=Sep	**X**	=Oct	**Y**	=Nov	**Z**	=Dec

L = Lot Code (1~9, A~Z)

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